US2881/2882

CMOS High Sensitivity Latch

Features and Benefits

- Chopper stabilized amplifier stage
- Optimized for BDC motor applications
- New miniature package / thin, high reliability package
- Operation down to 3.5V
- CMOS for optimum stability, quality, and cost
- Ultra low I_{DD} current

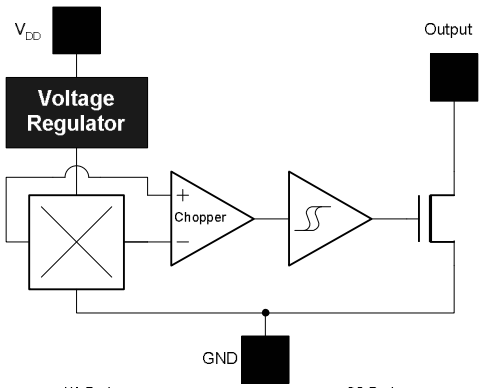
Applications

- Solid state switch
- Brushless DC motor commutation
- Speed sensing
- Linear position sensing
- Angular position sensing
- Current sensing

Ordering *Information*

Part No.	Temperature Suffix	Package
US2881 / US2882	E (-40°C to 85°C)	SO(SOT-23) or UA (TO-92 flat)
US2881 / US2882	L (-40°C to 150°C)	SO(SOT-23) or UA (TO-92 flat)

Functional Diagram



Note: *Static sensitive device; please observe ESD precautions. Reverse V_{DD} protection is not included. For reverse voltage protection, a 100W resistor in series with V_{DD} is recommended.*

Description

The design specifications and performance of the Melexis US2881 have been optimized for commutation applications in brushless DC motors and automotive speed sensing.

The output transistor will be latched on (B_{OP}) in the presence of a sufficiently strong South pole magnetic field facing the marked side of the package. Similarly, the output will be latched off (B_{RP}) in the presence of a North field. The SOT-23 device is reversed from the UA package. The SOT-23 output transistor will be latched on (B_{OP}) in the presence of a sufficiently strong North pole magnetic field subjected to the marked face.

US2881 and US2882 Electrical Specifications

DC operating parameters: T_A = 25°C, V_{DD} = 12V_{DC} (unless otherwise specified).

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Supply Voltage	V_{DD}	Operating	3.5		24	V
Supply Current	I_{DD}	B<B_{OP}	1.1	2.0	5.0	mA
Saturation Voltage	$V_{DS(on)}$	Vdd=12V,I_{OUT} = 20 mA, B>B_{OP}		0.4	0.5	V
Output Leakage	I_{OFF}	B<B_{RP}, V_{OUT} = 24V		0.01	10.0	µA
Output Rise Time	t_r	V_{DD} = 12V, R_L = 1.1KΩ, C_L = 20pf		0.04		µs
Output Fall Time	t_f	V_{DD} = 12V, R_L = 1.1KΩ, C_L = 20pf		0.18		µs

US2881 Magnetic Specifications

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Operating Point	B_{OP}	E/L UA, E/L SO, Ta= 25 Vdd=3.5 & 24 volts DC Vdd	0.5	2.0	4.5	mT
Release Point	B_{RP}	E/L UA, E/L SO, Ta= 25 Vdd=3.5 & 24 volts DC Vdd	-4.5	-2.0	-0.5	mT
Hysteresis	B_{hys}	E/L UA, E/L SO, Ta= 25 Vdd=3.5 & 24 volts DC Vdd	1.5	4.0	5.0	mT
Operating Point	B_{OP}	EUA, ESO, Ta= 85 Vdd=3.5 & 24 volts DC Vdd	-1.0	2.0	6.0	mT
Release Point	B_{RP}	EUA, ESO, Ta= 85 Vdd=3.5 & 24 volts DC Vdd	-6.0	-2.0	-1.0	mT
Hysteresis	B_{hys}	EUA, ESO, Ta= 85 Vdd=3.5 & 24 volts DC Vdd	1.5	4.0	5.5	mT
Operating Point	B_{OP}	LUA, LSO, Ta=150°C, Vdd=3.5 & 24 volts DC Vdd	-2.0	2.0	6.0	mT
Release Point	B_{RP}	LUA, LSO, Ta=150°C, Vdd=3.5 & 24 volts DC Vdd	-6.0	-2.0	2.0	mT
Hysteresis	B_{hys}	LUA, LSO, Ta=150°C, Vdd=3.5 & 24 volts DC Vdd	1.5	4.0	5.5	mT

Note: 1 mT = 10 Gauss.

US2882 Magnetic Specifications

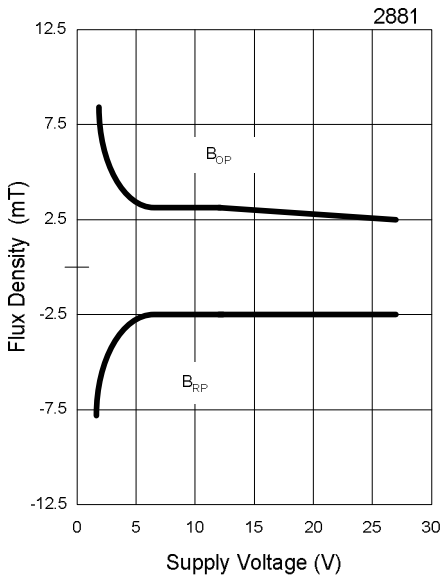
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Operating Point	B_{OP}	E/L UA, E/L SO, Ta= 25 Vdd=3.5 & 24 volts DC Vdd	-2.0	2.0	6.0	mT
Release Point	B_{RP}	E/L UA, E/L SO, Ta= 25 Vdd=3.5 & 24 volts DC Vdd	-6.0	-2.0	2.0	mT
Hysteresis	B_{hys}	E/L UA, E/L SO, Ta= 25 Vdd=3.5 & 24 volts DC Vdd	1.5	4.0	5.0	mT
Operating Point	B_{OP}	EUA, ESO, Ta= 85 Vdd=3.5 & 24 volts DC Vdd	-3.0	2.0	6.0	mT
Release Point	B_{RP}	EUA, ESO, Ta= 85 Vdd=3.5 & 24 volts DC Vdd	-6.0	-2.0	3.0	mT
Hysteresis	B_{hys}	EUA, ESO, Ta= 85 Vdd=3.5 & 24 volts DC Vdd	1.5	4.0	6.0	mT
Operating Point	B_{OP}	LUA, LSO, Ta=150°C, Vdd=3.5 & 24 volts DC Vdd	-3.5	2.0	6.0	mT
Release Point	B_{RP}	LUA, LSO, Ta=150°C, Vdd=3.5 & 24 volts DC Vdd	-6.0	-2.0	3.5	mT
Hysteresis	B_{hys}	LUA, LSO, Ta=150°C, Vdd=3.5 & 24 volts DC Vdd	1.5	4.0	6.0	mT

Absolute Maximum Ratings

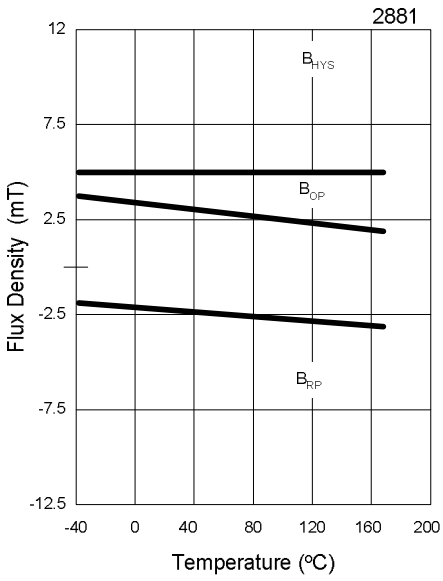
Supply Voltage (Operating), V_{DD}	24V
Supply Current (Fault), I_{DD}	50mA
Output Voltage, V_{OUT}	24V
Output Current (Fault), I_{OUT}	50mA
Power Dissipation, P_D	100mW
Operating Temperature Range, T_A	-40 to 150°C
Storage Temperature Range, T_S	-65 to 150°C
Maximum Junction Temp, T_J	175°C

Performance Graphs

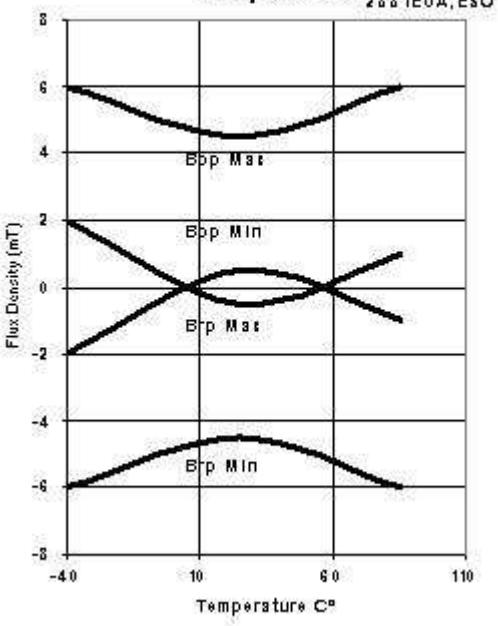
Typical Magnetic Switch Points versus Supply Voltage



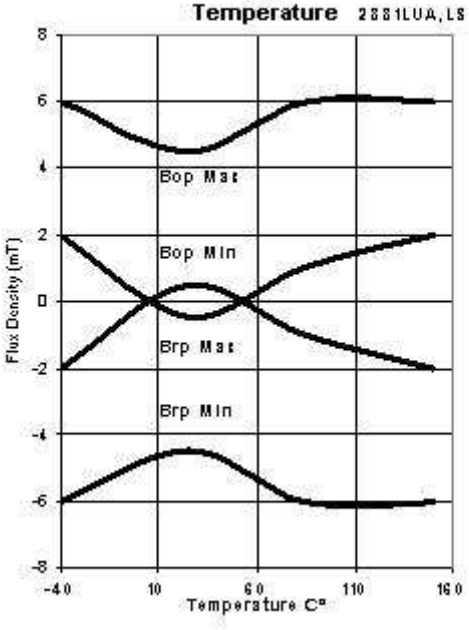
Typical Magnetic Switch Points versus Temperature

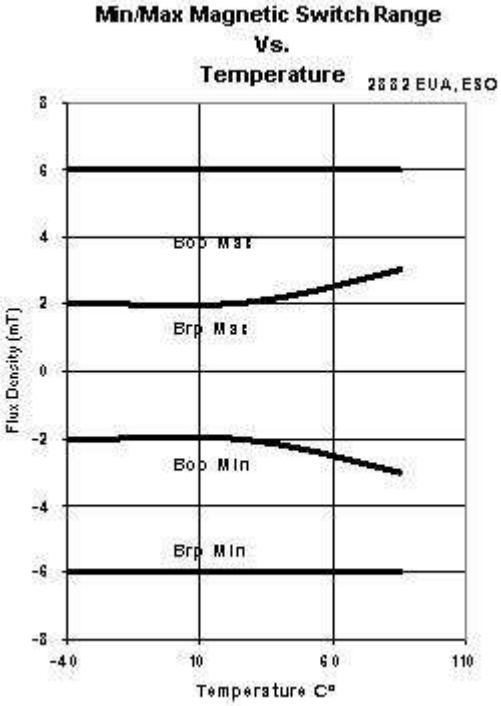


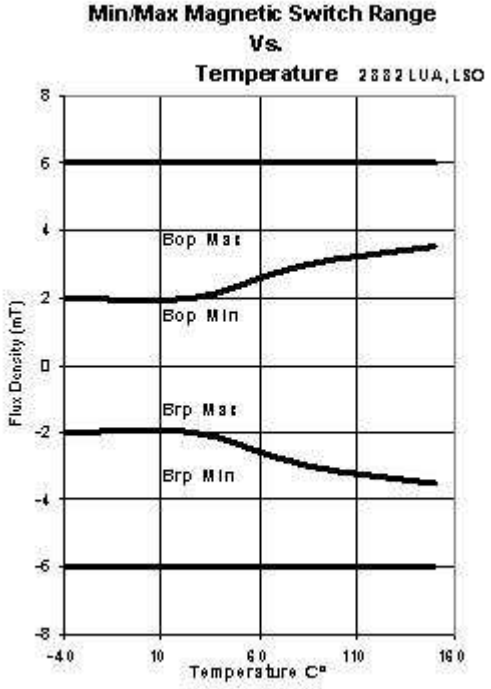
Min/Max Magnetic Switch Range Vs. Temperature

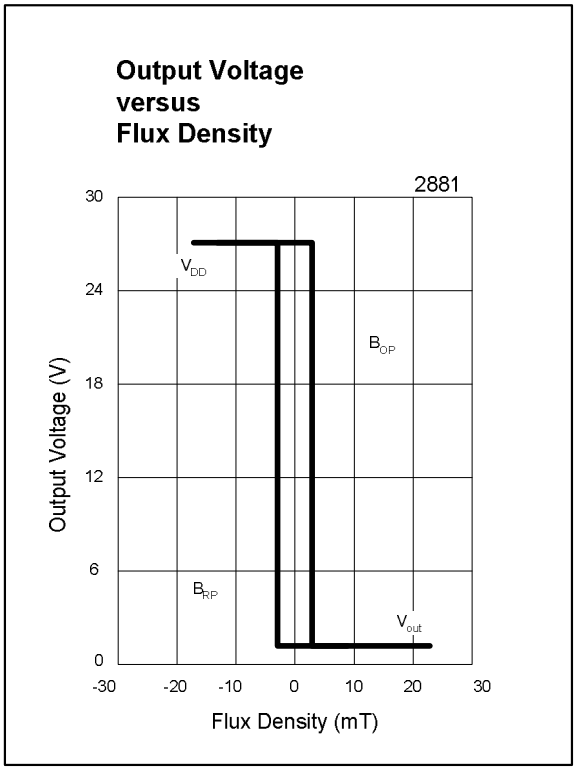


Min/Max Magnetic Switch Range Vs. Temperature



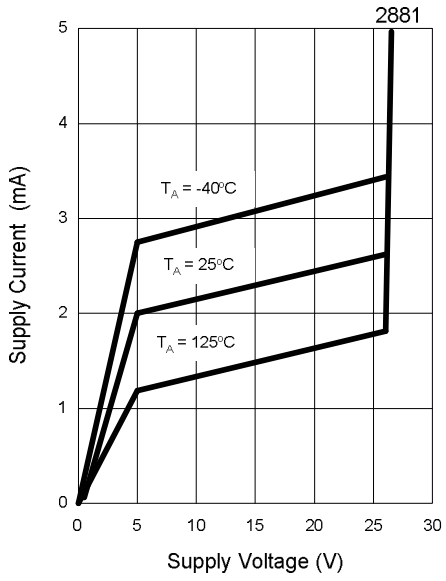

Min/Max Magnetic Switch Range
Vs.
Temperature
2882 EUA, ESO
Bop Max
Brp Max
Bop Min
Brp Min
Flux Density (mT)
Temperature C°
8
6
4
2
0
-2
-4
-6
-8
-40
10
60
110


Min/Max Magnetic Switch Range
Vs.
Temperature
2882 LUA, LSO
Bop Max
Bop Min
Brp Max
Brp Min
Flux Density (mT)
Temperature C°
8
6
4
2
0
-2
-4
-6
-8
-40
10
60
110
160

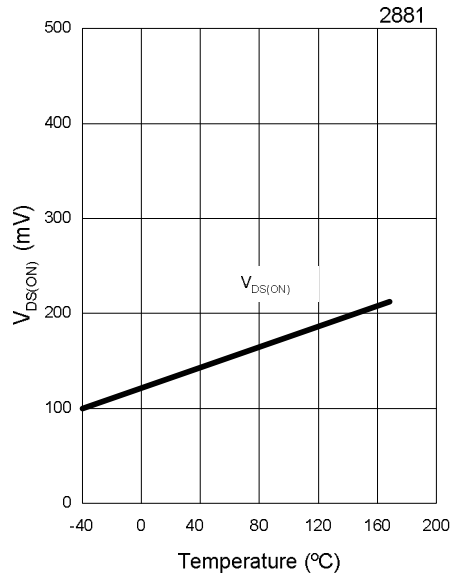

Output Voltage
versus
Flux Density
2881
V_{DD}
B_{OP}
B_{RP}
V_{out}
Output Voltage (V)
Flux Density (mT)
30
24
18
12
6
0
-30
-20
-10
0
10
20
30

Performance Graphs

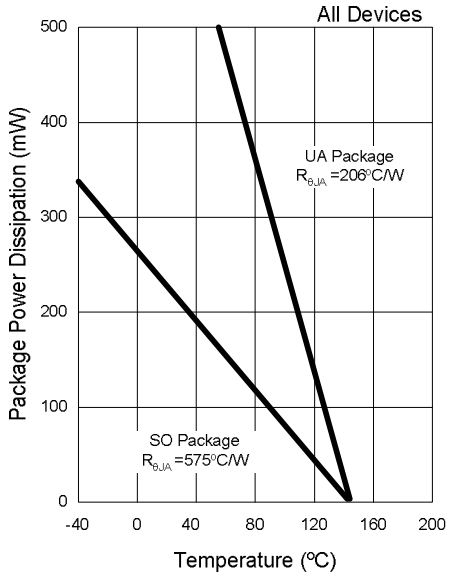
Typical Supply Current versus Supply Voltage



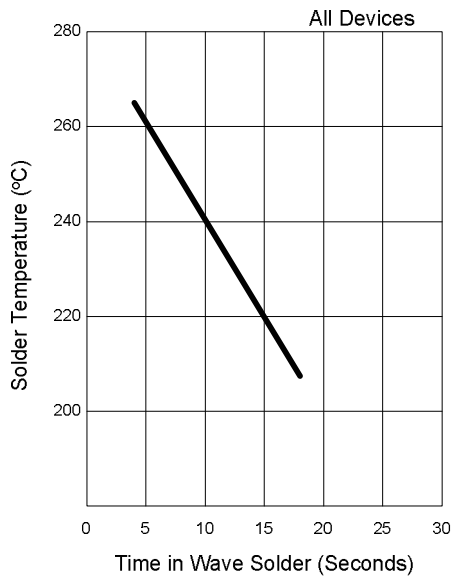
Typical Saturation Voltage versus Temperature
V_{DD} = 12 V, I_{OUT} = 20mA



Power Dissipation versus Temperature



Wave Soldering Parameters



Unique Features

CMOS Hall IC Technology

The Chopper Stabilized Amplifier, using switched capacitor techniques, eliminates the amplifier offset voltage, which in bipolar devices is a major source of temperature sensitive drift. CMOS makes this advanced technique possible.

The CMOS chip is also much smaller than the Bipolar chip, allowing very sophisticated circuitry to be placed in less space. The small chip size also contributes to lower physical stress and less power consumption.

Installation

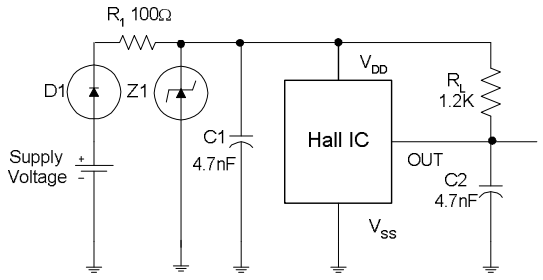
Consider temperature coefficients of Hall IC and magnetics, as well as air gap and life time variations. Observe temperature limits during wave soldering.

Application Comments

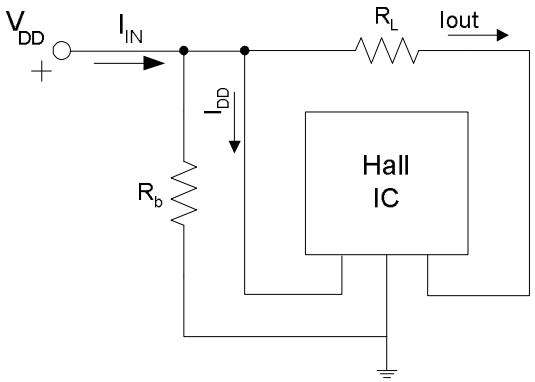
If reverse supply protection is desired, use a resistor in series with the V_{DD} pin. The resistor will limit the Supply Current (Fault), I_{DD}, to 50mA. For severe EMC conditions, use the application circuit below.

Applications Examples

Automotive and Severe Environment Protection Circuit



Two Wire Optional Current Biasing Circuit

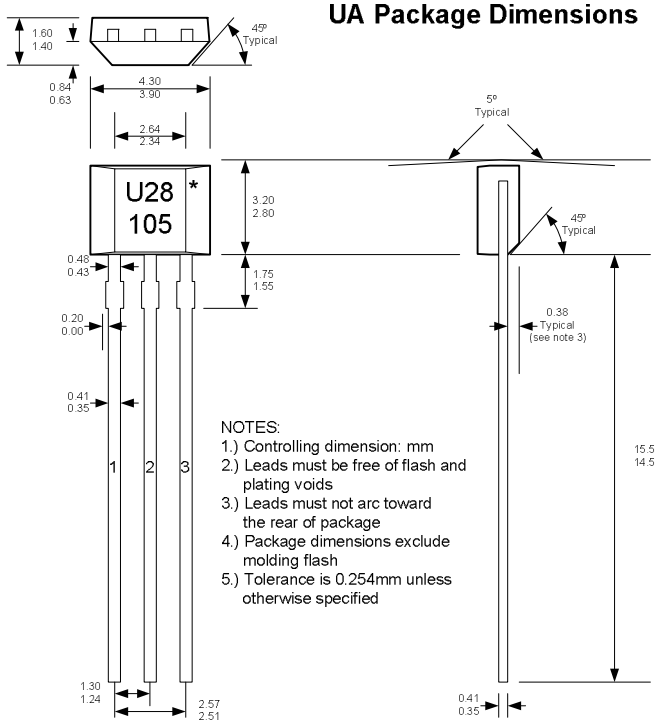


The resistors R_b and R_L can be used to bias the input current, Iin. Refer to the part specification for limiting values. This circuit will help in getting the precise ON and OFF currents desired.

B_{RP} = Ioff = (V_{DD} / Rb + I_{DD})
B_{OP} = Ion = (Ioff + V_{DD} / R_L)

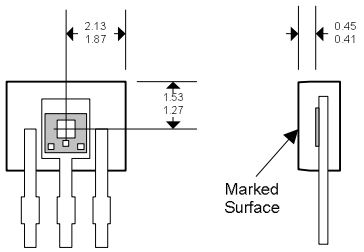
Physical Characteristics

UA Package Dimensions



NOTES:
1.) Controlling dimension: mm
2.) Leads must be free of flash and plating voids
3.) Leads must not arc toward the rear of package
4.) Package dimensions exclude molding flash
5.) Tolerance is 0.254mm unless otherwise specified

UA Hall Plate / Chip Location



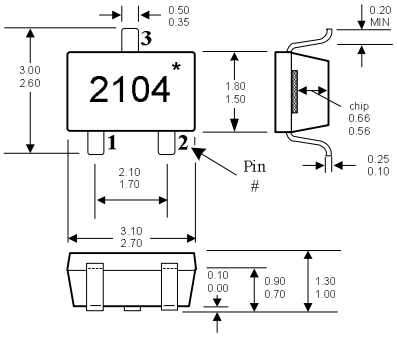
All Dimensions in millimeters

* MARKING:
Line 1:
1st digit (U) = Supplier (Melexis)
2nd and 3rd digits (28) = Series (2880)

Line 2:
1st digit (1) = Year (2001)
2nd and 3rd digits(05) = Week of Year

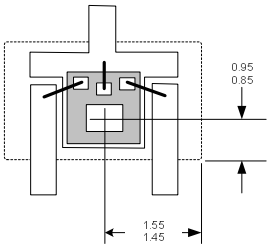
PINOUT:
Pin 1 V_{DD}
Pin 2 GND
Pin 3 Output

SOT-23 Package Dimensions (Top View)



NOTES:
1. MARKING:
   1st Digit (2) = Series (2881)
   2nd Digit(1) = Year - 2001
   Last Digits (04) = Week of Year
2. PINOUT (See Top View at left):
   Pin 1 VDD
   Pin 2 Output
   Pin 3 GND
3. Controlling dimension: mm.
4. Lead thickness after solder plating will be 0.254 mm maximum.
5. Package dimensions exclude molding flash.
6. The end flash shall not exceed 0.127 mm on each side of package.
7. Tolerance is +/- 0.254 mm unless otherwise specified.

SOT-23 Hall Plate / Chip Location (Bottom View)



Reliability Information

Melexis devices are classified and qualified regarding suitability for infrared, vapor phase and wave soldering with usual (63/37 SnPb-) solder (melting point at 183degC).
The following test methods are applied:

IPC/JEDEC J-STD-020A (issue April 1999)
Moisture/Reflow Sensitivity Classification For Nonhermetic Solid State Surface Mount Devices
CECC00802 (issue 1994)
Standard Method For The Specification of Surface Mounting Components (SMDs) of Assessed Quality
MIL 883 Method 2003 / JEDEC-STD-22 Test Method B102
Solderability

For all soldering technologies deviating from above mentioned standard conditions (regarding peak temperature, temperature gradient, temperature profile etc) additional classification and qualification tests have to be agreed upon with Melexis.

The application of Wave Soldering for SMD's is allowed only after consulting Melexis regarding assurance of adhesive strength between device and board.

For more information on manufacturability/solderability see quality page at our website: http://www.melexis.com/

ESD Precautions

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD).
Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

Disclaimer

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